

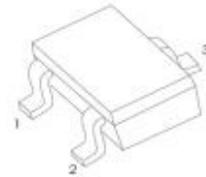
TRANSISTOR (NPN)

FEATURES

Complementary to MMBT5401T

Ideal for medium power amplification and switching

SOT - 523



- 1. BASE
- 2. EMITTER
- 3. COLLECTOR

MARKING: G1

MAXIMUM RATINGS ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

| Symbol | Parameter | Value | Units |
|-----------|-------------------------------|---------|--------------------|
| V_{CBO} | Collector-Base Voltage | 180 | V |
| V_{CEO} | Collector-Emitter Voltage | 160 | V |
| V_{EBO} | Emitter-Base Voltage | 6 | V |
| I_C | Collector Current -Continuous | 0.6 | A |
| P_C | Collector Power Dissipation | 200 | mW |
| T_j | Junction Temperature | 150 | $^{\circ}\text{C}$ |
| T_{stg} | Storage Temperature | -55-150 | $^{\circ}\text{C}$ |

ELECTRICAL CHARACTERISTICS ($T_{amb}=25^{\circ}\text{C}$ unless otherwise specified)

| Parameter | Symbol | Test conditions | MIN | TYP | MAX | UNIT |
|--------------------------------------|-----------------|---|-----|-----|------|------|
| Collector-base breakdown voltage | $V_{(BR)CBO}$ | $I_C=100\mu\text{A}$, $I_E=0$ | 180 | | | V |
| Collector-emitter breakdown voltage | $V_{(BR)CEO}^*$ | $I_C=1\text{mA}$, $I_B=0$ | 160 | | | V |
| Emitter-base breakdown voltage | $V_{(BR)EBO}$ | $I_E=10\mu\text{A}$, $I_C=0$ | 6 | | | V |
| Collector cut-off current | I_{CBO} | $V_{CB}=120\text{V}$, $I_E=0$ | | | 50 | nA |
| Emitter cut-off current | I_{EBO} | $V_{EB}=4\text{V}$, $I_C=0$ | | | 50 | nA |
| DC current gain | h_{FE1}^* | $V_{CE}=5\text{V}$, $I_C=1\text{mA}$ | 80 | | | |
| | h_{FE2}^* | $V_{CE}=5\text{V}$, $I_C=10\text{mA}$ | 100 | | 300 | |
| | h_{FE3}^* | $V_{CE}=5\text{V}$, $I_C=50\text{mA}$ | 50 | | | |
| Collector-emitter saturation voltage | V_{CEsat}^* | $I_C=10\text{mA}$, $I_B=1\text{mA}$ | | | 0.15 | V |
| | | $I_C=50\text{mA}$, $I_B=5\text{mA}$ | | | 0.2 | |
| Base-emitter saturation voltage | V_{BEsat}^* | $I_C=10\text{mA}$, $I_B=1\text{mA}$ | | | 1 | V |
| | | $I_C=50\text{mA}$, $I_B=5\text{mA}$ | | | 1 | |
| Transition frequency | f_T | $V_{CE}=10\text{V}$, $I_C=10\text{mA}$, $f=100\text{MHz}$ | 100 | | 300 | MHz |
| Collector output capacitance | C_{ob} | $V_{CB}=10\text{V}$, $I_E=0$, $f=1\text{MHz}$ | | | 6 | pF |
| Input capacitance | C_{ib} | $V_{BE}=0.5\text{V}$, $I_C=0$, $f=1\text{MHz}$ | | | 20 | pF |
| Noise figure | NF | $V_{CE}=5\text{V}$, $I_C=0.25\text{mA}$, $f=10\text{Hz}$ to 15.7KHz , $R_s=1\text{k}\Omega$ | | | 8 | dB |

Typical Characteristics

